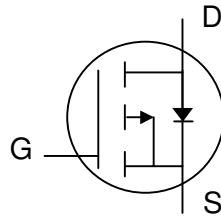




P-channel Enhancement-mode Power MOSFET

- Simple Drive Requirement**
- Low On-Resistance**
- Fast Switching Performance**
- RoHS-compliant, halogen-free**

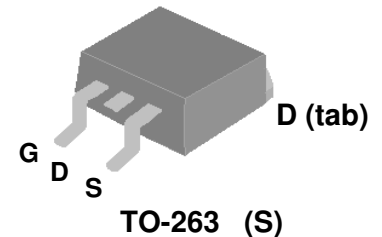


BV_{DSS}	-60V
$R_{DS(ON)}$	12.5mΩ
I_D	-105A

Description

Advanced Power MOSFETs from APEC provide the designer with the best combination of fast switching, low on-resistance and cost-effectiveness.

The AP9571GS-HF-3 is in the TO-263 package, which is widely used for commercial and industrial surface-mount applications, and is well suited for low voltage applications such as DC/DC converters.



Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	-60	V
V_{GS}	Gate-Source Voltage	±20	V
I_D at $T_C=25^\circ C$	Continuous Drain Current	-105	A
I_D at $T_C=100^\circ C$	Continuous Drain Current	-67	A
I_{DM}	Pulsed Drain Current ¹	-300	A
P_D at $T_C=25^\circ C$	Total Power Dissipation	250	W
P_D at $T_A=25^\circ C$	Total Power Dissipation ³	3.13	W
T_{STG}	Storage Temperature Range	-55 to 150	°C
T_J	Operating Junction Temperature Range	-55 to 150	°C

Thermal Data

Symbol	Parameter	Value	Units
Rthj-c	Maximum Thermal Resistance, Junction-case	0.5	°C/W
Rthj-a	Maximum Thermal Resistance, Junction-ambient (PCB mount) ³	40	°C/W

Ordering Information

AP9571GS-HF-3TR : in RoHS-compliant, halogen-free TO-263, shipped on tape and reel (800 pcs/reel)



Electrical Specifications at $T_j=25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=-250\mu A$	-60	-	-	V
$R_{DS(ON)}$	Static Drain-Source On-Resistance ²	$V_{GS}=-10V, I_D=-30A$	-	-	12.5	m Ω
		$V_{GS}=-4.5V, I_D=-20A$	-	-	17	m Ω
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1	-	-3	V
g_{fs}	Forward Transconductance	$V_{DS}=-10V, I_D=-30A$	-	60	-	S
I_{DSS}	Drain-Source Leakage Current	$V_{DS}=-48V, V_{GS}=0V$	-	-	-25	μA
I_{GSS}	Gate-Source Leakage	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 100	nA
Q_g	Total Gate Charge	$I_D=-30A$	-	63	100	nC
Q_{gs}	Gate-Source Charge	$V_{DS}=-48V$	-	11	-	nC
Q_{gd}	Gate-Drain ("Miller") Charge	$V_{GS}=-4.5V$	-	37	-	nC
$t_{d(on)}$	Turn-on Delay Time	$V_{DS}=-30V$	-	12.5	-	ns
t_r	Rise Time	$I_D=-30A$	-	54	-	ns
$t_{d(off)}$	Turn-off Delay Time	$R_G=3.3\Omega$	-	125	-	ns
t_f	Fall Time	$V_{GS}=-10V$	-	140	-	ns
C_{iss}	Input Capacitance	$V_{GS}=0V$	-	6000	9600	pF
C_{oss}	Output Capacitance	$V_{DS}=-25V$	-	940	-	pF
C_{rss}	Reverse Transfer Capacitance	$f=1.0\text{MHz}$	-	320	-	pF
R_g	Gate Resistance	$f=1.0\text{MHz}$	-	4.3	8.6	Ω

Source-Drain Diode

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
V_{SD}	Forward On Voltage ²	$I_S=-30A, V_{GS}=0V$	-	-	-1.3	V
t_{rr}	Reverse Recovery Time	$I_S=-10A, V_{GS}=0V,$	-	60	-	ns
Q_{rr}	Reverse Recovery Charge	$di/dt=-100A/\mu s$	-	90	-	nC

1. Pulse width limited by maximum junction temperature.
2. Pulse test
3. Surface mounted on 1in² copper pad of FR4 board

THIS PRODUCT IS SENSITIVE TO ELECTROSTATIC DISCHARGE, PLEASE HANDLE WITH CAUTION.

USE OF THIS PRODUCT AS A CRITICAL COMPONENT IN LIFE SUPPORT OR OTHER SIMILAR SYSTEMS IS NOT AUTHORIZED.

APEC DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

APEC RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN.



Typical Electrical Characteristics

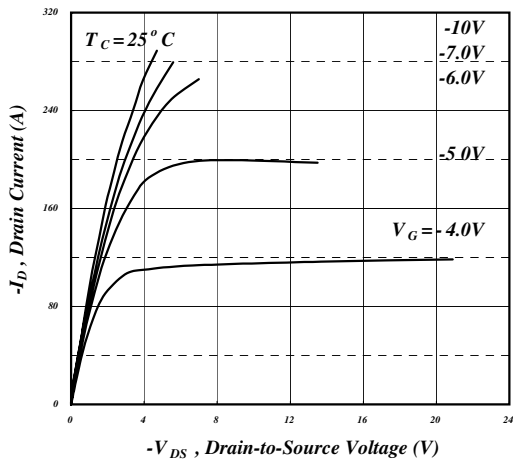


Fig 1. Typical Output Characteristics

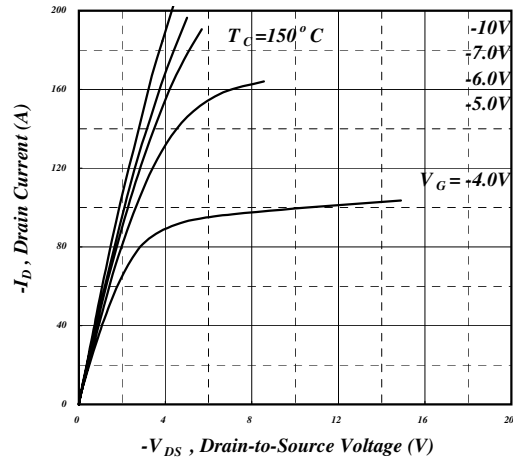


Fig 2. Typical Output Characteristics

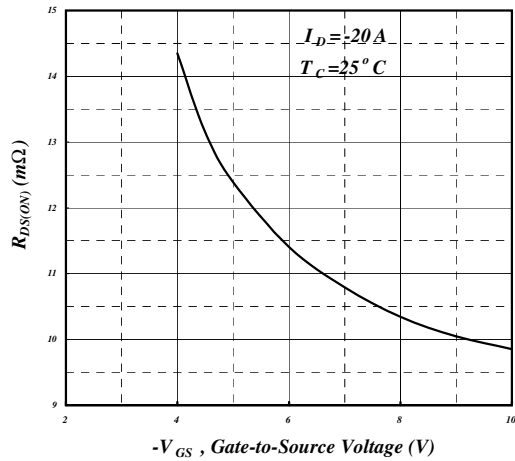


Fig 3. On-Resistance vs. Gate Voltage

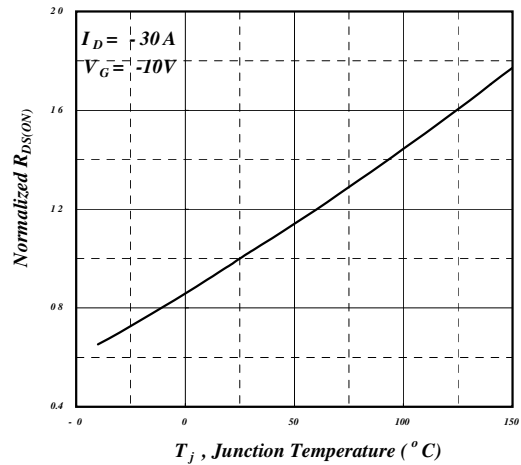


Fig 4. Normalized On-Resistance vs. Junction Temperature

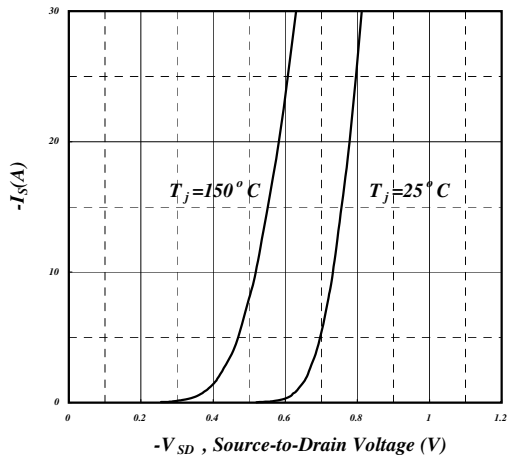


Fig 5. Forward Characteristic of Reverse Diode

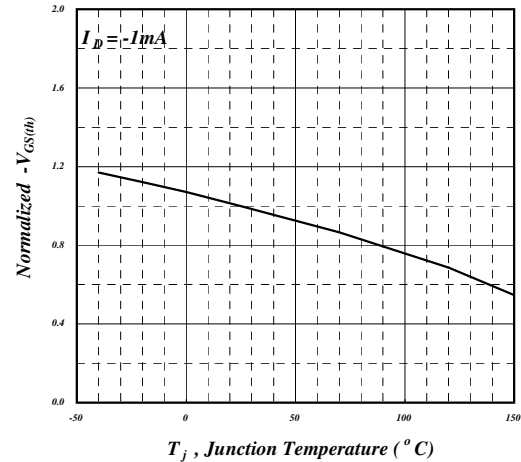


Fig 6. Gate Threshold Voltage vs. Junction Temperature



Typical Electrical Characteristics (cont.)

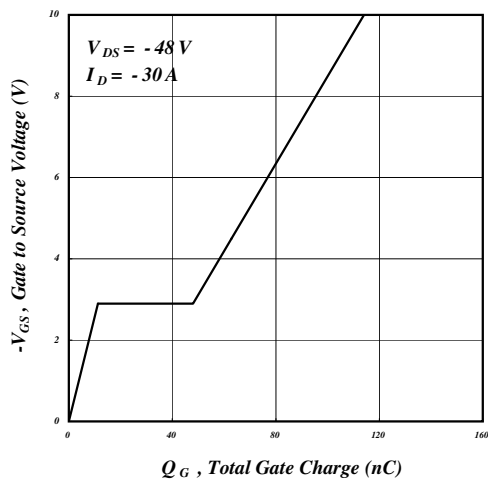


Fig 7. Gate Charge Characteristics

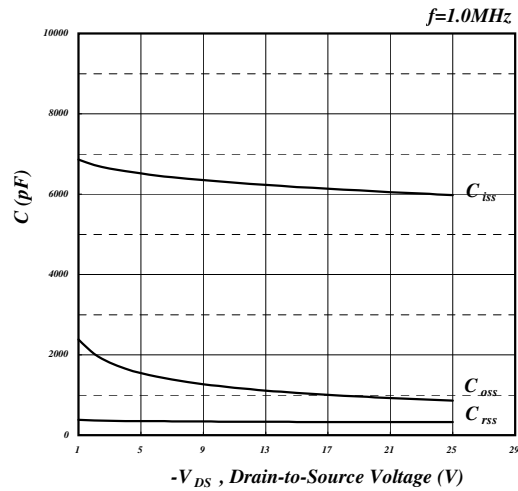


Fig 8. Typical Capacitance Characteristics

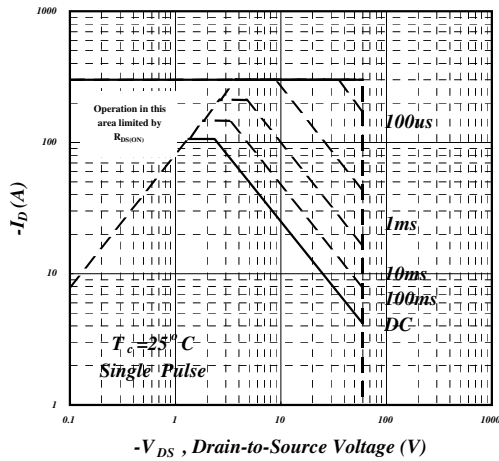


Fig 9. Maximum Safe Operating Area

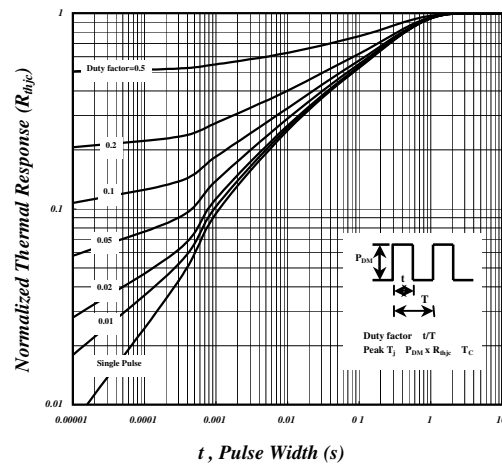


Fig 10. Effective Transient Thermal Impedance

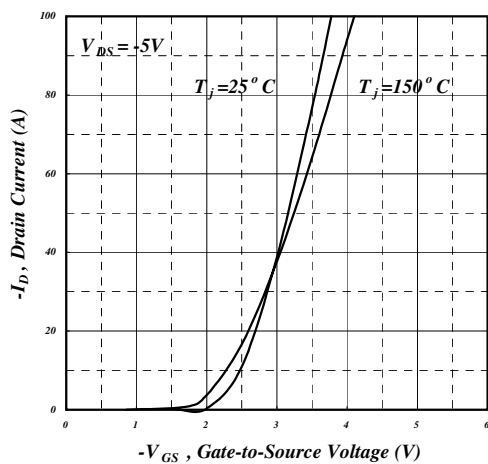


Fig 11. Transfer Characteristics

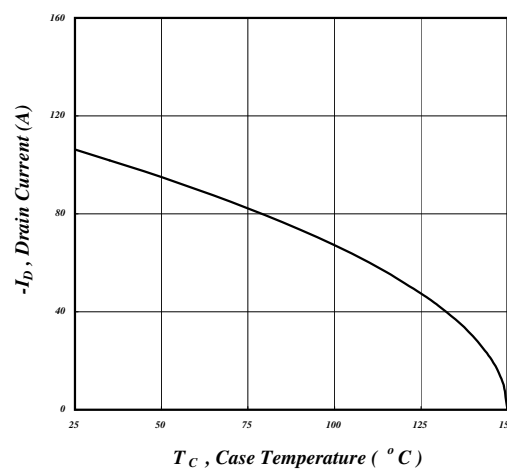
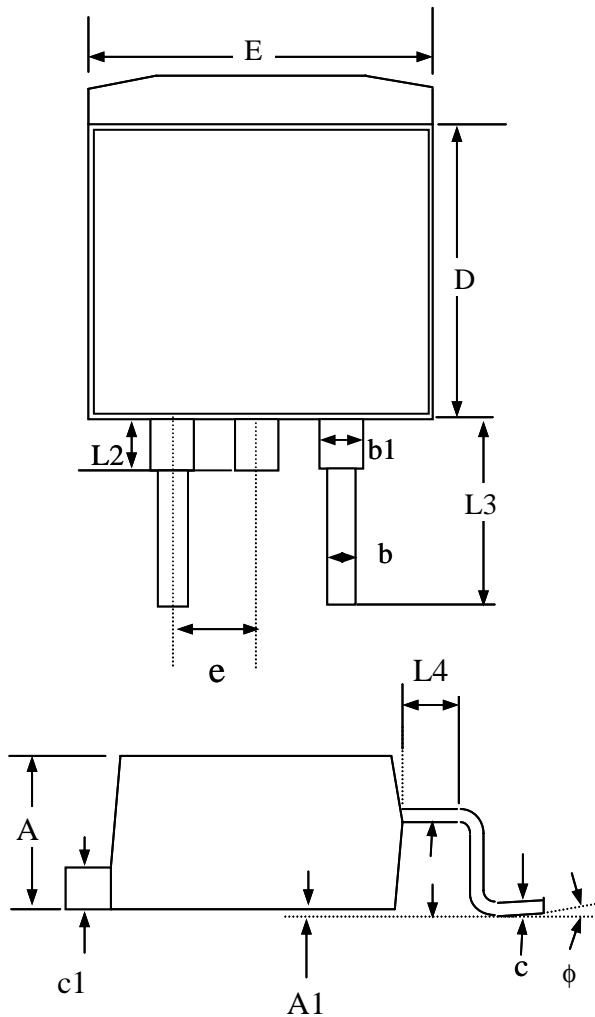


Fig 12. Maximum Continuous Drain Current vs. Case Temperature



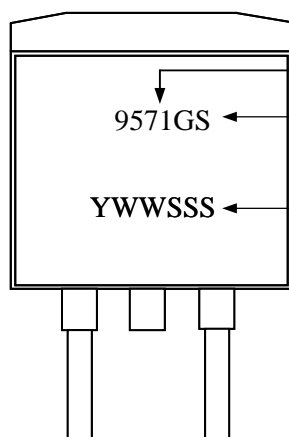
Package Dimensions: TO-263



SYMBOLS	Millimeters		
	MIN	NOM	MAX
A	4.25	4.75	5.20
A1	0.00	0.15	0.30
A2	2.20	2.45	2.70
b	0.70	0.90	1.10
b1	1.07	1.27	1.47
c	0.30	0.45	0.60
c1	1.15	1.30	1.45
D	8.30	8.90	9.40
E	9.70	10.10	10.50
e	2.04	2.54	3.04
L2	-----	1.50	-----
L3	4.50	4.90	5.30
L4	-----	1.50	----

1. All dimensions are in millimeters.
2. Dimensions do not include mold protrusions.

Marking Information:



Product: AP9571

9571GS

Package code:

GS = RoHS-compliant halogen-free TO-263

YWWSSS

Date Code (YWWSSS)

Y : Last digit of the year

WW : Work week

SSS : Lot code sequence